TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT257P,TC74ACT257F,TC74ACT257FN

2-Channel Multiplexer (3-state)

The TC74ACT257 is an advanced high speed CMOS MULTIPLEXER fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL or NMOS and CMOS output voltage levels.

Each is composed of four independent 2-channel multiplexers with common SELECT and $\overline{OUTPUT} ENABLE$ (\overline{OE}).

If \overline{OE} is set low, the outputs are held in a high-impedance state. When SELECT is set low, "A" data inputs are enabled.

Conversely, when SELECT is high, "B" data inputs are enabled.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 5.8 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A (max)$ at $Ta = 25^{\circ}C$
- Compatible with TTL outputs: VIL = 0.8 V (max)

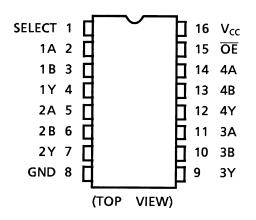
 $V_{IH} = 2.0 V (min)$

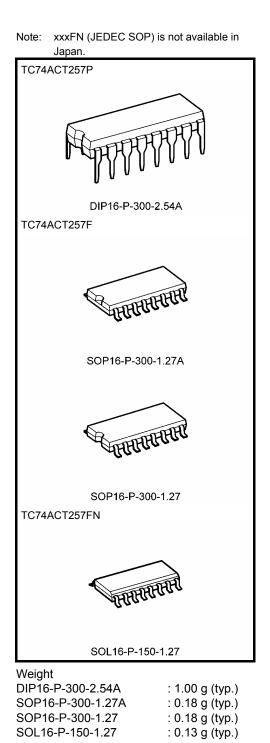
• Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24 \text{ mA} (\text{min})$ Capability of driving 50 Ω

transmission lines.

- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F257

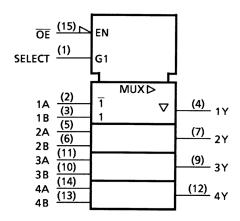
Pin Assignment





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IEC Logic Symbol



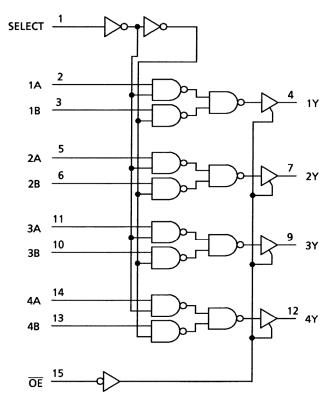
Truth Table

	Output				
ŌĒ	SELECT	A B		Y	
Н	Х	Х	Х	Z	
L	L	L	Х	L	
L	L	Н	Х	Н	
L	Н	Х	L	L	
L	Н	Х	Н	Н	

X: Don't care

Z: High impedance

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	IOK	±50	mA
DC output current	IOUT	±50	mA
DC V _{CC} /ground current	ICC	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	–65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
Characteristics	Symbol				V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V _{IH}		—			2.0	_	_	2.0	_	V
Low-level input voltage	V _{IL}	—			4.5 to 5.5	_	_	0.8	_	0.8	V
	V _{OH}	VIN	I _{OH} = -50 μA		4.5	4.4	4.5	_	4.4	_	
High-level output voltage		= V _{IH} or V _{IL}	I _{OH} = -24 mA		4.5	3.94	—	—	3.80	—	V
			I _{OH} = -75 mA	(Note)	5.5	—	—	—	3.85	—	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 50 \ \mu A$		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I _{OL} = 24 mA		4.5	—	—	0.36	—	0.44	V
			l _{OL} = 75 mA	(Note)	5.5	—	—	—	—	1.65	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$			5.5	_	_	±0.5	_	±5.0	μΑ
Input leakage current	IIN	$V_{IN} = V_{CC}$ or GND			5.5		_	±0.1	_	±1.0	μA
	Icc	$V_{IN} = V_{CC} \text{ or } GND$			5.5	_	_	8.0	_	80.0	μA
Quiescent supply current	IC	Per input: $V_{IN} = 3.4 \text{ V}$ Other input: V_{CC} or GND			5.5	_	_	1.35	_	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

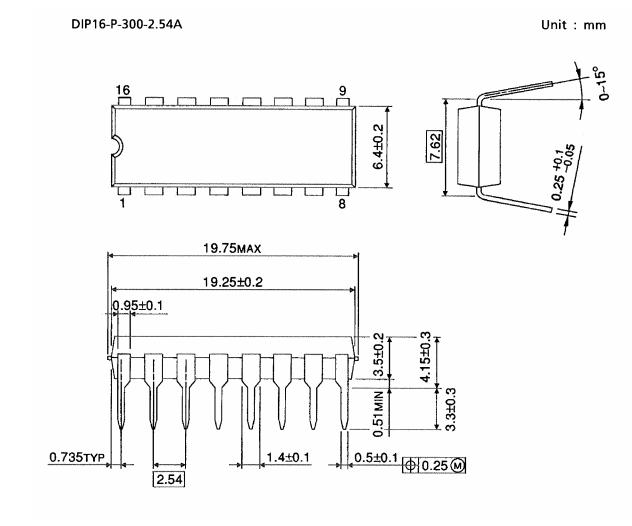
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = –40 to 85°C		Unit
	- ,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay time (A, B-Y)	^t pLH ^t pHL	_	5.0 ± 0.5	_	6.5	9.6	1.0	11.0	ns
Propagation delay time (SELECT-Y)	t _{pLH} t _{pHL}		5.0 ± 0.5		7.8	11.4	1.0	13.0	ns
Output enable time	t _{pZL} t _{pZH}	_	5.0 ± 0.5	_	6.3	9.6	1.0	11.0	ns
Output disable time	t _{pLZ} t _{pHZ}	_	5.0 ± 0.5	_	6.3	8.8	1.0	10.0	ns
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Output capacitance	C _{OUT}	_			10				pF
Power dissipation capacitance	C _{PD} (Note)	_		_	57	_	_	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per bit)

Package Dimensions



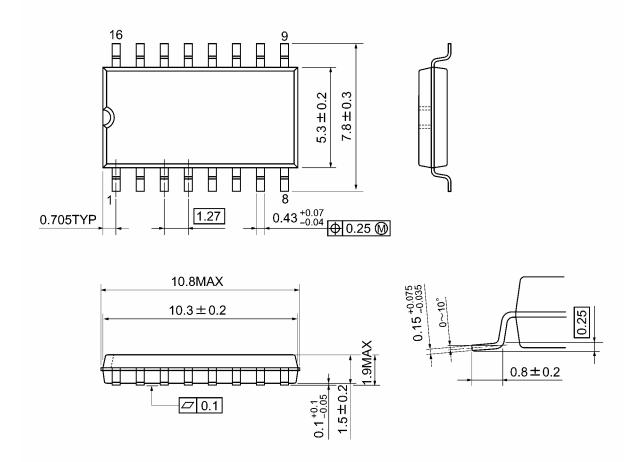
Weight: 1.00 g (typ.)



Package Dimensions

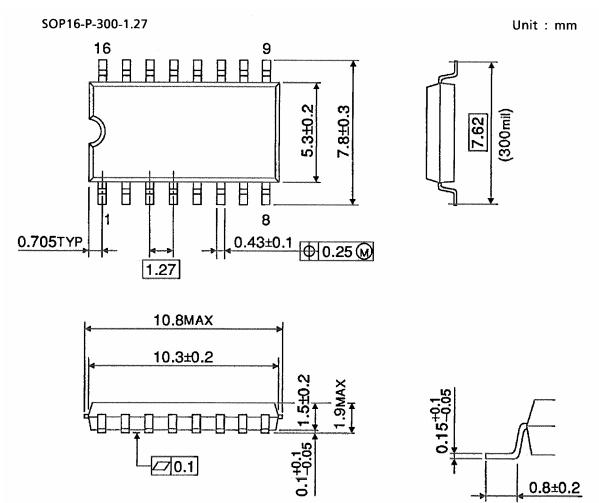
SOP16-P-300-1.27A

Unit: mm



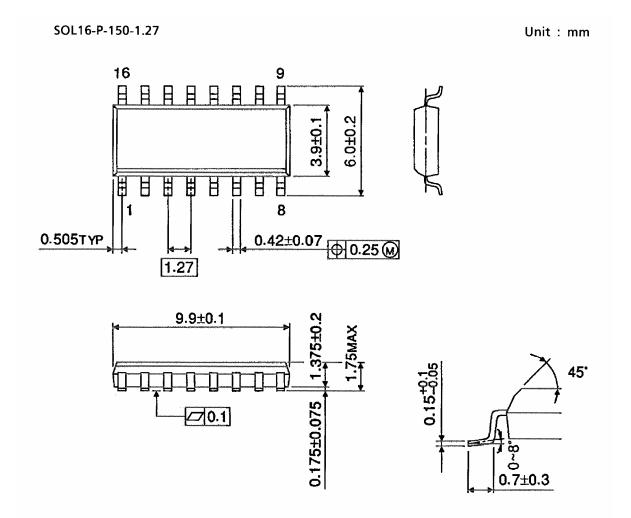
Weight: 0.18 g (typ.)

Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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Note: Lead (Pb)-Free Packages DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27

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